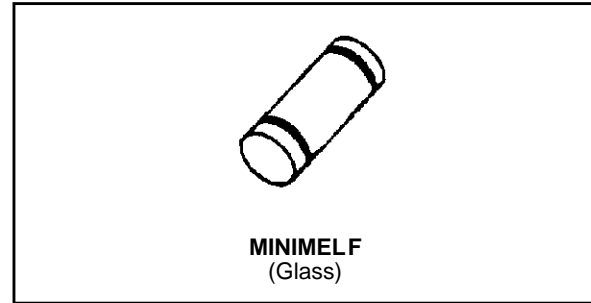


SMALL SIGNAL SCHOTTKY DIODE
DESCRIPTION

Metal to silicon junction diode featuring high break-down, low turn-on voltage and ultrafast switching. Primarily intended for high level UHF/VHF detection and pulse application with broad dynamic range. Matched batches are available on request.


ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		70	V
I_F	Forward Continuous Current	$T_i = 25\text{ }^\circ\text{C}$	15	mA
I_{FSM}	Surge non Repetitive Forward Current	$t_p \leq 1\text{ s}$	50	mA
T_{stg} T_j	Storage and Junction Temperature Range		- 65 to 200 - 65 to 200	$^\circ\text{C}$
T_L	Maximum Temperature for Soldering during 15s		260	$^\circ\text{C}$

THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
$R_{th(j-l)}$	Junction-leads	400	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS
STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
V_{BR}	$T_{amb} = 25\text{ }^\circ\text{C}$	$I_R = 10\text{ }\mu\text{A}$	70			V
V_F^*	$T_{amb} = 25\text{ }^\circ\text{C}$	$I_F = 1\text{ mA}$			0.41	V
	$T_{amb} = 25\text{ }^\circ\text{C}$	$I_F = 15\text{ mA}$			1	
I_R^*	$T_{amb} = 25\text{ }^\circ\text{C}$	$V_R = 50\text{ V}$			0.2	μA

DYNAMIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
C	$T_{amb} = 25\text{ }^\circ\text{C}$	$V_R = 0\text{ V}$	$f = 1\text{ MHz}$			2	pF
τ	$T_{amb} = 25\text{ }^\circ\text{C}$	$I_F = 5\text{ mA}$	Krakauer Method			100	ps

* Pulse test: $t_p \leq 300\text{ }\mu\text{s}$ $\delta < 2\%$.

Matched batches available on request. Test conditions (forward voltage and/or capacitance) according to customer specification.

Fig.1 : Forward current versus forward voltage at low level (typical values).

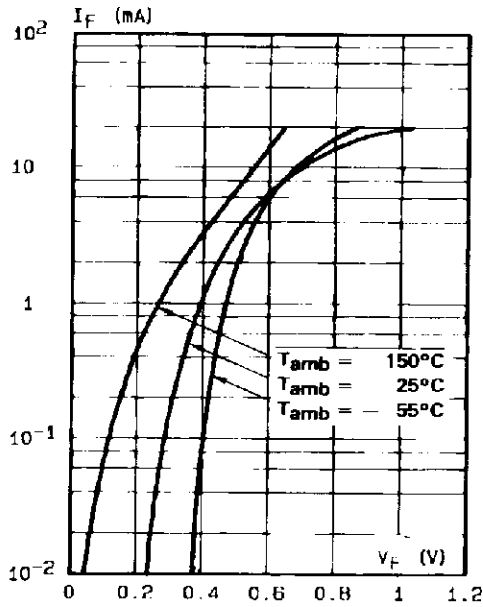


Fig.2 : Capacitance C versus reverse applied voltage V_R (typical values).

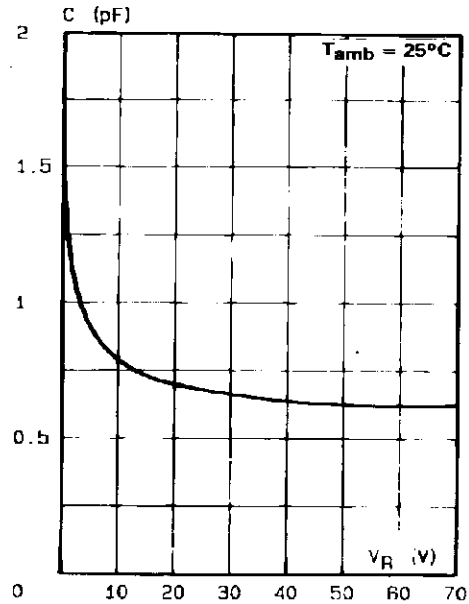


Fig.3 : Reverse current versus ambient temperature.

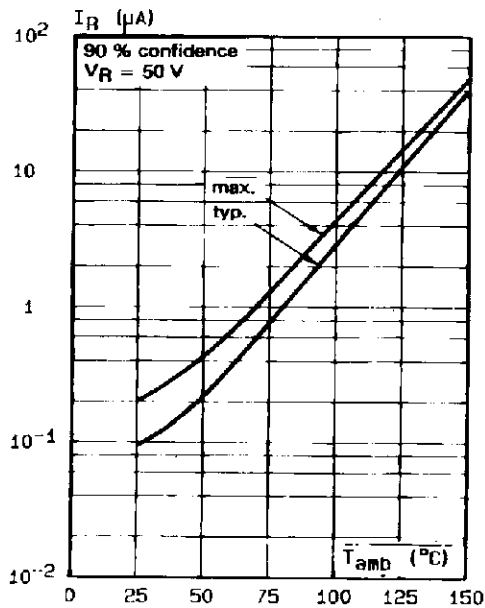
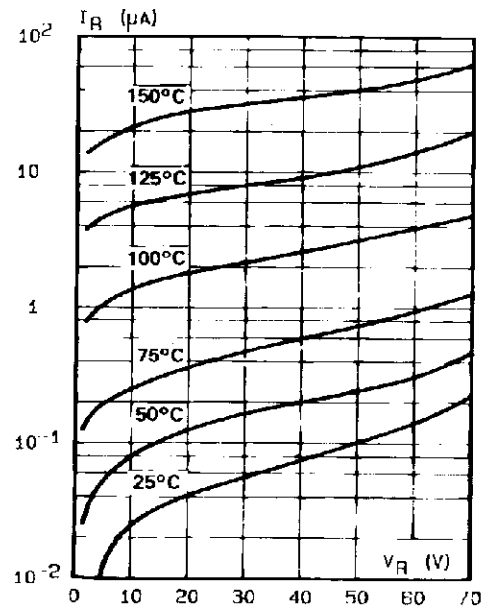


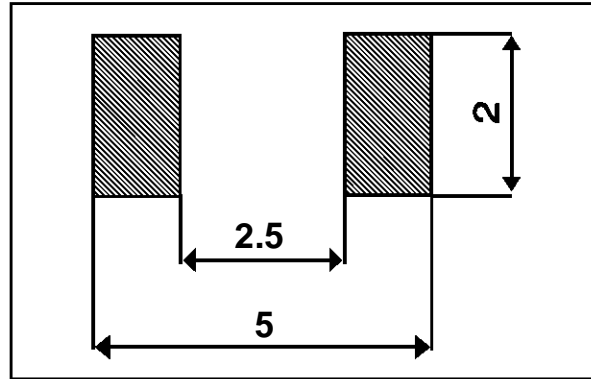
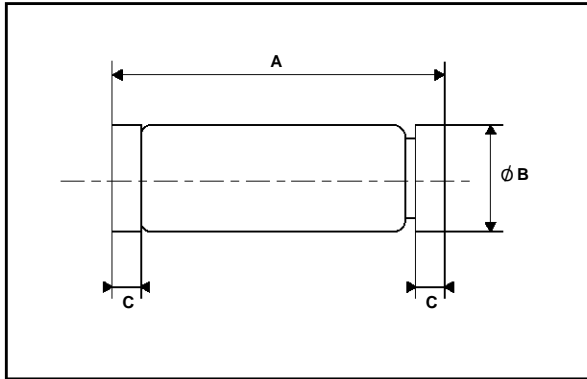
Fig.4 : Reverse current versus continuous reverse voltage (typical values).



PACKAGE MECHANICAL DATA

FOOT PRINT DIMENSIONS (Millimeter)

MINIMELF Glass



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	3.3	3.6	0.130	0.142
B	1.59	1.62	0.063	0.064
C	0.4	0.5	0.016	0.020

Marking: ring at cathode end.
Weight: 0.05g

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